

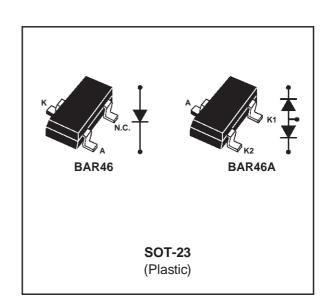
# SMALL SIGNAL SCHOTTKY DIODES

#### **FEATURES AND BENEFITS**

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- LOW FORWARD VOLTAGE DROP
- SURFACE MOUNT DEVICE



High voltage Schottky rectifier suited for SLIC protection during the card insertion operation.



## ABSOLUTE RATINGS(limiting values)

Symbol	Parameter	Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage	100	V
lF	Continuous forward current	150	mA
P <sub>tot</sub>	Power dissipation (note 1)	230	mW
T <sub>stg</sub>	Maximum storage temperature range	- 65 to +150	°C
Tj	Maximum operating junction temperature *	150	°C
TL	Maximum temperature for soldering during	260	°C

Note 1: for double diodes, Ptot is the total dissipation of both diodes.

\* : 
$$\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$$
 thermal runaway condition for a diode on its own heatsink

#### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rth(j-a)	Junction-ambient*	500	°C/W

<sup>\*</sup> Mounted on epoxy board, with recommended pad layout.

June 1999 - Ed: 2A

# BAR46/BAR46A

## **ELECTRICAL CHARACTERISTICS**

## STATIC CHARACTERISTICS

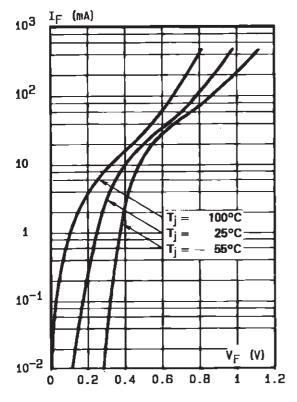
Symbol	Test conditions			Тур.	Max.	Unit
$V_{BR}$	Tj = 25 °C	I <sub>R</sub> = 100 μA	100			V
V <sub>F</sub> *	Tj = 25 °C	I <sub>F</sub> = 0.1 mA			0.25	V
	Tj = 25 °C	I <sub>F</sub> = 10 mA			0.45	
	Tj = 25 °C	$I_F = 250 \text{mA}$			1	
I <sub>R</sub> **	Tj = 25 °C	V <sub>R</sub> = 1.5 V			0.5	μΑ
	Tj = 60 °C				5	
	Tj = 25 °C	V <sub>R</sub> = 10 V			0.8	
	Tj = 60 °C				7.5	
	Tj = 25 °C	V <sub>R</sub> = 50 V			2	
	Tj = 60 °C				15	
	Tj = 25 °C	V <sub>R</sub> = 75 V			5	
	Tj = 60 °C				20	

## DYNAMIC CHARACTERISTICS

5	Symbol	Test conditions			Min.	Тур.	Max.	Unit
	С	Tj = 25 °C	$V_R = 0 V$	F = 1MHz		10		pF
		Tj = 25 °C	V <sub>R</sub> = 1 V			6		

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**Fig. 1:** Forward current versus forward voltage at different temperatures (typical values).



**Fig. 3:** Reverse current versus junction temperature (typical values).

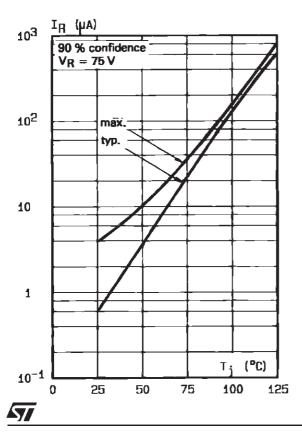
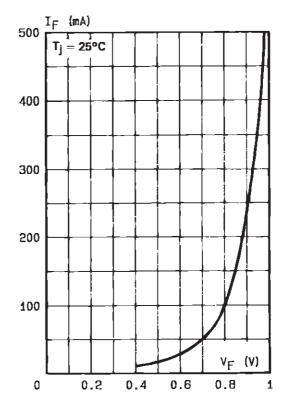


Fig. 2: Forward current versus forward voltage (typical values).



**Fig. 4:** Reverse current versus continuous reverse voltage (typical values).

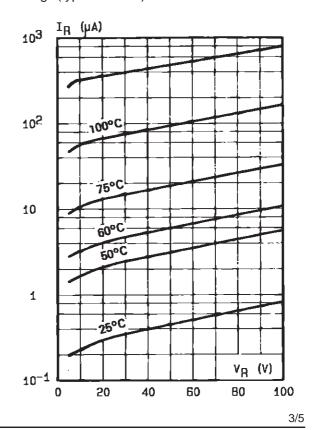
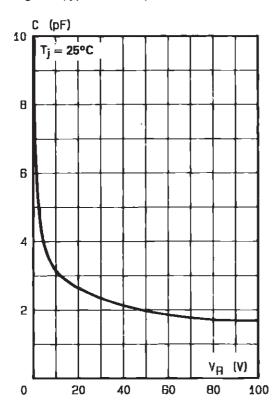


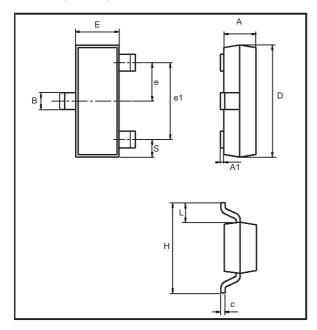
Fig. 5: Capacitance C versus reverse applied voltage  $V_{\text{R}}$  (typical values).



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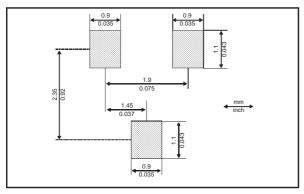
#### **PACKAGE MECHANICAL DATA**

SOT 23 (Plastic)



	DIMENSIONS				
REF.	Millin	neters	Inches		
	Min.	Max.	Min.	Max.	
А	0.89	1.4	0.035	0.055	
A1	0	0.1	0	0.004	
В	0.3	0.51	0.012	0.02	
С	0.085	0.18	0.003	0.007	
D	2.75	3.04	0.108	0.12	
е	0.85	1.05	0.033	0.041	
e1	1.7	2.1	0.067	0.083	
E	1.2	1.6	0.047	0.063	
Н	2.1	2.75	0.083	0.108	
L	0.6 typ.		0.024 typ.		
S	0.35	0.65	0.014	0.026	

#### **FOOT PRINT DIMENSIONS** (Millimeter)



Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BAR46	S46	SOT-23	0.01g	3000	Tape & reel
BAR46A	A46	SOT-23	0.01g	3000	Tape & reel

# ■ Epoxy meets UL94,V0

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